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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/632,736	08/01/2003	Yuri V. Melnik	700623-3003	3873
7590 05/20/2005		EXAMINER		
David G. Beck			MOORE, KARLA A	
Bingham McCutchen, LLP 18th Floor			ART UNIT	PAPER NUMBER
Three Embarcadero Center			1763	
San Francisco, CA 94111			DATE MAILED: 05/20/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
·	10/632,736	MELNIK ET AL.	
Office Action Summary	Examiner	Art Unit	
	Karla Moore	1763	
The MAILING DATE of this communication a			
Period for Reply			
A SHORTENED STATUTORY PERIOD FOR REF THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory perions - Failure to reply within the set or extended period for reply will, by state than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).	I. 1.136(a). In no event, however, may a pply within the statutory minimum of thi Id will apply and will expire SIX (6) MOI ute, cause the application to become A	reply be timely filed rty (30) days will be considered timely. NTHS from the mailing date of this communicatio BANDONED (35 U.S.C. & 133).	n.
Status			
1) Responsive to communication(s) filed on 24	November 2004.		
	nis action is non-final.		
3) Since this application is in condition for allow		ters, prosecution as to the merits is	s
closed in accordance with the practice under	Ex parte Quayle, 1935 C.). 11, 453 O.G. 213.	
Disposition of Claims			
4)⊠ Claim(s) <u>1-13</u> is/are pending in the application	· on		
4a) Of the above claim(s) is/are withdr	· ·		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-13</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and	or election requirement.		
Application Papers			
9) The specification is objected to by the Examin	ner.		
10)⊠ The drawing(s) filed on <u>01 August 2003</u> is/are		piected to by the Examiner	
Applicant may not request that any objection to the		_	
Replacement drawing sheet(s) including the corre		- ·	d).
11) The oath or declaration is objected to by the I		· ·	/-
Priority under 35 U.S.C. § 119			
12)☐ Acknowledgment is made of a claim for foreig	un ndority under 35 U.S.C. i	\$ 110(a) (d) or (f)	
a) ☐ All b) ☐ Some * c) ☐ None of:	gn phonty under 33 U.S.C. (; 113(a)-(u) Ul (l).	
1.☐ Certified copies of the priority docume	nts have been received		
2. Certified copies of the priority document		application No	
3. Copies of the certified copies of the pri			
application from the International Bure		, 55577 55 77 tillo Hational Otage	
* See the attached detailed Office action for a lis	, ,,,	received.	
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Attachment(s)	_		
1) X Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) La Interview S	Summary (PTO-413) s)/Mail Date	
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08		nformal Patent Application (PTO-152)	
Paper No(s)/Mail Date <u>0803</u> .	6) 🗌 Other:		

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 3. Claims 1-5, 7-8 and 12-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,993,542 to Yanashima et al in view of U.S. Patent No. 4,853,078 to Miyazaki. Yanashima et al. disclose a reactor capable of growing a gallium containing single crystal substantially as claimed in Figure 7 and comprising: a multi-zone heater (141); a growth zone (between bottom surface of partition plate 113 and bottom of chamber and from edge of partition plate 113 to far right of chamber), wherein said multi-zone heater is capable of maintaining at least one substrate within said growth zone at a temperature greater than 850°C (column 12, rows 25 and 26); a gallium source within a gallium source zone (between partition plates 113 and 114); a halide reaction gas source (labeled "HCl") coupled to said multi-zone gallium source zone; an inert gas source (labeled "N₂") coupled to said multi-zone gallium source zone to transport a first reaction product from said multi-zone gallium source zone to said growth zone; and a reaction gas source (labeled "NH₃") coupled to said growth zone.
- 5. However, Yanashima et al. fail to teach an extended gallium source within a multi-zone gallium source zone, wherein said multi-zone heater is capable of maintaining a first portion of said extended

gallium source zone at a first temperature greater than 450°C while simultaneously maintaining a second portion of said extended gallium source at a second temperature in the range of 30°C to 100°C, wherein upon reaction said second portion comprises at least 50 percent of said extended gallium source.

- 6. Mayazaki teaches using an elongated source for crystal deposition with a temperature profile created by heating the source using a multi-zone heater (abstract; column 3, rows 34-41; column 5, rows 5-15) for the purpose of growing a crystal having little change in composition and in deviation from stoichiometry.
- 7. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided an elongated source with a temperature profile as needed for performing a specific processing in Yanashima et al. in order to grow a crystal having little change in composition and in deviation from stoichiometry as taught by Mayazaki.
- 8. Examiner notes that the courts have ruled that claims directed to apparatus must be distinguished from the prior art in terms of structure rather than function. In re Danly, 263 F.2d 844, 847, 120 USPQ 528, 531 (CCPA 1959). Applicant's claims contain numerous recitations drawn to a method of using the apparatus and a results produced by using the method. These are not viewed as structural limitations as they do not recite any additional structure present in the apparatus or expand upon structures previously recited. It is noted that the courts have also ruled that a claim containing a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all the structural limitations of the claim. Ex parte Masham, 2 USPQ2d 1647 (Bd. Pat. App. & Inter. 1987).
- 9. With respect to claims 2-3, again Examiner notes that Applicant's recitations involving a method for using the apparatus do not distinguish themselves from the prior art in terms of structure and the courts have ruled that claims directed to apparatus must be distinguished from the prior art in terms of structure rather than function. In re Danly, 263 F.2d 844, 847, 120 USPQ 528, 531 (CCPA 1959).
- 15. With respect to claims 4, Yanashima discloses the invention substantially as claimed and as described above. Additionally, Yanashima discloses an aluminum source zone (above partition 116),

wherein said halide reaction gas source is coupled to the aluminum source zone and means for heating (141) the aluminum source zone are provided, as well. The aluminum source is an organic metal compound supplied from a bubbler (120) using a carrier gas. Yanashima further teaches that Group 3 elements may be supplied to the reactor as either organic metal compounds or simple elements (column 3, rows 16-18).

- 16. However, Yanashima fails to explicitly teach the aluminum source with the inert gas source (described above) coupled to it.
- 17. Yanashima et al. teaches repeatedly in his disclosure all of the simple elements sources coupled to the same inert gas source for the purpose of using nitrogen as a carrier gas (column 11, rows 38-39 and 44-45).
- 18. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made, if the aluminum source had been a simple element, to have provided said inert gas source coupled to said aluminum source in Yanashima in order to use the nitrogen as a carrier gas as taught by Yanashima et al.
- 19. With respect to claim 5, the courts have ruled that the mere duplication of parts has no patentable significance unless a new and unexpected result is produced. In re Harza, 274 F. 2d 669, 124 USPQ 378 (CCPA 1960).
- 20. With respect to claims 7-8, Yanashima and Miyazaki disclose the invention substantially as claimed and as described above. Additionally, Yanashima et al. disclose use of an acceptor impurity source (Be, Mg, Ca, Zn and Cd) or a donor impurity source (C, Si, Ge and Sn) (column 3, rows 5-15). Were the either of the impurity sources used in the reactor, the heater (141) would obviously act as heating means.
- 21. However, Yanashima et al. and Miyazaki fail to teach the impurity source zones coupled to said inert gas source.
- 22. Yanashima et al. teach other source zones coupled to the inert gas source for the purpose of using nitrogen gas as a carrier gas as detailed above.

- 23. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided an impurity source zone coupled to the inert gas source in Yanashima et al. and Miyazaki in order to use the nitrogen as a carrier gas as taught by Yanashima et al.
- 24. With respect to claims 12 and 13, the halide gas source supplies HCl gas and the reaction gas source supplies ammonia gas as claimed and described above. However, Examiner notes that the courts have ruled that expressions relating the apparatus to contents thereof during an intended operation are of no significance in determining patentability of the apparatus claim. Ex parte Thibault, 164 USPQ 666, 667 (Bd. App. 1969).
- 25. Claim 6 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yanashima et al. and Miyazaki as applied to claims 1-5, 7-8 and 12-13 above, and further in view of U.S. Patent No. 4,268,842 to Jacob et al.
- 26. Yanashima et al. and Miyazaki disclose the invention substantially as claimed and as described above.
- 27. However, Yanashima et al. and Miyazaki fail to teach the multi-zone heater as a resistive heater.
- 28. Jacob et al. teach the use of a multi-zone resistive heating furnace for the purpose of heating both a gallium source and a substrate in a reactor (column 11, rows 10-19).
- 29. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a multi-zone resistive heater in Yanashima et al. and Miyazaki in order to heat a gallium source and a substrate within a reactor as taught by Jacob et al.
- 30. Claims 9-11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yanashima et al. and Miyazaki as applied to claims 1-5, 7-8 and 12-13 above, and further in view of U.S. Patent No. 5,266,127 to Imaizumi et al.
- 31. Yanashima et al. and Miyazaki disclose the invention substantially as claimed and as described above.

- 32. However, Yanashima et al. and Miyazawa fail to teach the reactor further comprising means for transferring said at least one substrate within said growth zone to a second growth zone.
- 33. Imaizumi et al. disclose the use of means for transferring a substrate between two growth zones for the purpose of growing two different layers on a single substrate in a single system (see Figure 9; column 2, rows 3-13).
- 34. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided means for transferring a substrate between to growth zones in Yanashima et al. and Miyazaki et al. in order to grow two different layers on a single substrate in a single system as taught by Imaizumi et al.
- 35. With respect to claim 10, specific details are not given regarding heating the second growth zone in Imaizumi et al.
- 36. Yanashima et al. teach using an external multi-zone heater for the purpose of providing a temperature gradient in a lengthwise direction (column 11, rows 48-52).
- 37. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have used the external multi-zone heater in Yanashima et al., Miyazaki and Imaizumi to heat both the first and second growth in order to provide each with a temperature gradient in a lengthwise direction as taught by Yanashima et al.
- 38. With respect to claim 11, which contains recitations drawn to a specific method that could be carried out using the apparatus, Examiner notes that the courts have ruled that claims directed to apparatus must be distinguished from the prior art in terms of structure rather than function. <u>In re Danly</u>, 263 F.2d 844, 847, 120 USPQ 528, 531 (CCPA 1959).
- 39. In general, Examiner notes that many of Applicant's claims are drawn to ideal temperatures for carrying out an intended operation. The prior art cited above has the capability to attain these

temperatures and therefore has been applied against the claimed invention with respect to their structures, rather than their intended operation.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Karla Moore whose telephone number is 571.272.1440. The examiner can normally be reached on Monday-Friday, 8:30am-5:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on 571.272.1435. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Karla Moore Patent Examiner Art Unit 1763 16 May 2005